

BT151-1000RT

Rev.02 - 06 September 2021

Product data sheet

1. General description

SCR

Planar passivated Silicon Controlled Rectifier (SCR) in a TO220 plastic package intended for use in applications requiring very high bidirectional blocking voltage capability, high junction temperature capability and high thermal cycling performance.

2. Features and benefits

- · High junction operating temperature capability
- High thermal cycling performance
- Planar passivated for voltage ruggedness and reliability
- Very high bidirectional blocking voltage capability

3. Applications

- Capacitive Discharge Ignition (CDI)
- Crowbar protection
- Inrush protection
- Motor control
- Voltage regulation

4. Quick reference data

Table 1. Q	uick reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{DRM}	repetitive peak off-state voltage		-	-	1000	V
V_{RRM}	repetitive peak reverse voltage		-	-	1000	V
I _{TSM}	non-repetitive peak on- state current	half sine wave; $T_{j(init)}$ = 25 °C; t_p = 10 ms; Fig. 4; Fig. 5	-	-	120	A
		half sine wave; $T_{j(init)}$ = 25 °C; t_p = 8.3 ms	-	-	132	А
Tj	junction temperature		-	-	150	°C
$I_{\mathrm{T}(\mathrm{AV})}$	average on-state current	half sine wave; T _{mb} ≤ 134 °C	-	-	7.5	A
$I_{T(RMS)}$	RMS on-state current	half sine wave; T _{mb} ≤ 134 °C; <u>Fig. 1</u> ; <u>Fig. 2</u> ; <u>Fig. 3</u>	-	-	12	A
Static ch	aracteristics					
I _{GT}	gate trigger current	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T}_{j} = 25 \text{ °C}; \text{ Fig. 7}$	-	2	15	mA
Dynamic	characteristics	I I	 			1
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 670 V; T _j = 150 °C; (V_{DM} = 67% of V_{DRM}); exponential waveform; gate open circuit; Fig. 12	-	300	-	V/µs

5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode	mb	N 1
2	А	anode		А₩К
3	G	gate		G sym037
mb	A	mounting base; connected to anode		

6. Ordering information

Table 3. Ordering information								
Type number	Package	Orderable part number		Small packing		Package		
	name		method	quantity	version	issue date		
BT151-1000RT	TO220	BT151-1000RT,127	Tube	50	SOT78	13-Jun-2008		

7. Marking

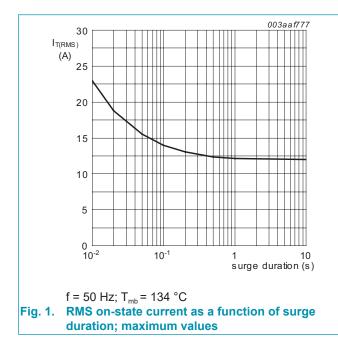
Table 4. Marking codes						
Type number	Marking codes					
	Assembly factory: d	Assembly factory: A				
BT151-1000RT	BT151 1000RT PJdxxxx xx	BT151 1000RT PJAxxxx xx				

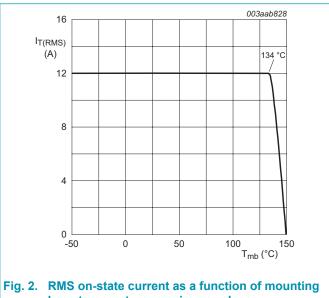
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

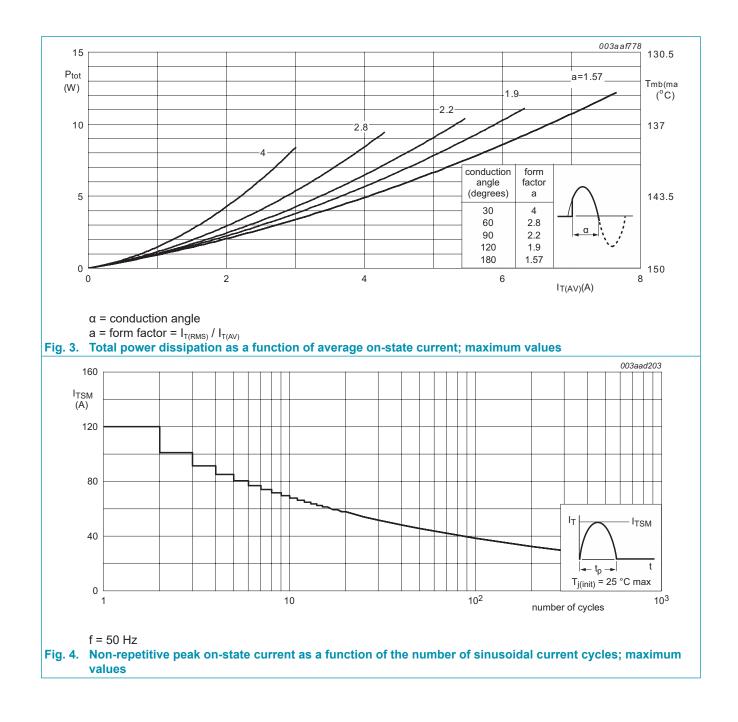
Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage		-	1000	V
V_{RRM}	repetitive peak reverse voltage		-	1000	V
I _{T(AV)}	average on-state current	half sine wave; T _{mb} ≤ 134 °C	-	8	А
$\mathbf{I}_{\mathrm{T(RMS)}}$	RMS on-state current	half sine wave; T _{mb} ≤ 134 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u>	-	12.5	A
I _{TSM}	non-repetitive peak on- state current	half sine wave; $T_{j(init)} = 25 \text{ °C}$; $t_p = 10 \text{ ms}$; Fig. 4; Fig. 5	-	120	A
		half sine wave; $T_{j(init)} = 25 \text{ °C}$; $t_p = 8.3 \text{ ms}$	-	132	А
l ² t	I ² t for fusing	t _p = 10 ms; sine-wave pulse	-	72	A ² s
dl _T /dt	rate of rise of on-state current	I _G = 30 mA	-	50	A/µs
I _{GM}	peak gate current		-	2	А
V _{RGM}	peak reverse gate voltage		-	5	V
P _{GM}	peak gate power		-	5	W
$P_{G(AV)}$	average gate power	over any 20 ms period	-	0.5	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	150	°C

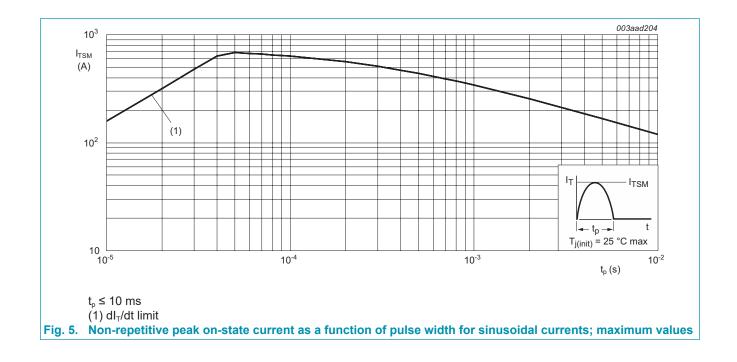




base temperature; maximum values

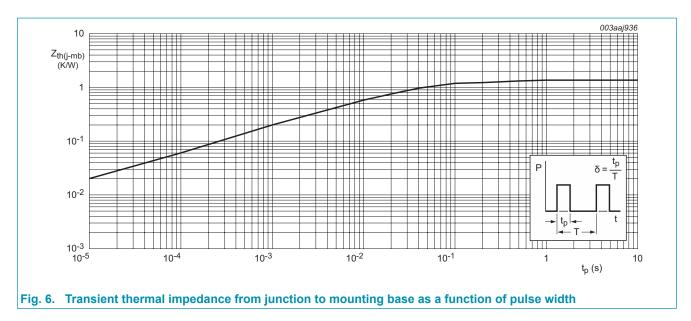
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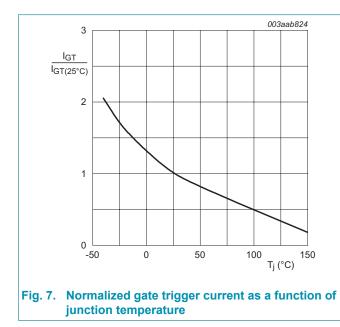
9. Thermal characteristics

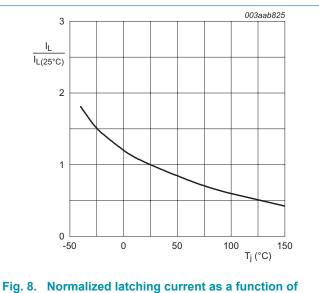
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	<u>Fig. 6</u>	-	-	1.3	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient free air	in free air	-	60	-	K/W



10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics					
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 7</u>	-	2	15	mA
I _L	latching current	V _D = 12 V; I _G = 0.1 A; T _j = 25 °C; <u>Fig. 8</u>	-	10	40	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	7	20	mA
V _T	on-state voltage	I _T = 23 A; T _j = 25 °C; <u>Fig. 10</u>	 -	1.4	1.75	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 11</u>	 -	0.6	1	V
		V _D = 1000V; I _T = 0.1 A;T _j = 150 °C	 0.25	0.4	-	V
I _D	off-state current	V _D = 1000 V; T _j = 150 °C	 -	0.5	2.5	mA
I _R	reverse current	V _R = 1000 V; T _j = 150 °C	 -	0.5	2.5	mA
Dynamic	characteristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 670 V; T _j = 150 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit; Fig. 12	-	300	-	V/µs
t _{gt}	gate-controlled turn-on time	$I_{TM} = 40 \text{ A}; V_{D} = 1000 \text{ V}; I_{G} = 0.1 \text{ A};$ $dI_{G}/dt = 5 \text{ A}/\mu\text{s}; T_{j} = 25 ^{\circ}\text{C}$	-	2	-	μs
t _q	commutated turn-off time	$V_{DM} = 670 \text{ V}; \text{ T}_{j} = 150 \text{ °C}; \text{ I}_{TM} = 20 \text{ A}; \text{ V}_{R} = 25 \text{ V}; (dI_{T}/dt)_{M} = 30 \text{ A}/\mu\text{s}; dV_{D}/dt = 50 \text{ V}/\mu\text{s}; \text{ R}_{GK(ext)} = 100 \Omega; (V_{DM} = 67\% \text{ of } V_{DRM})$	-	70	-	μs

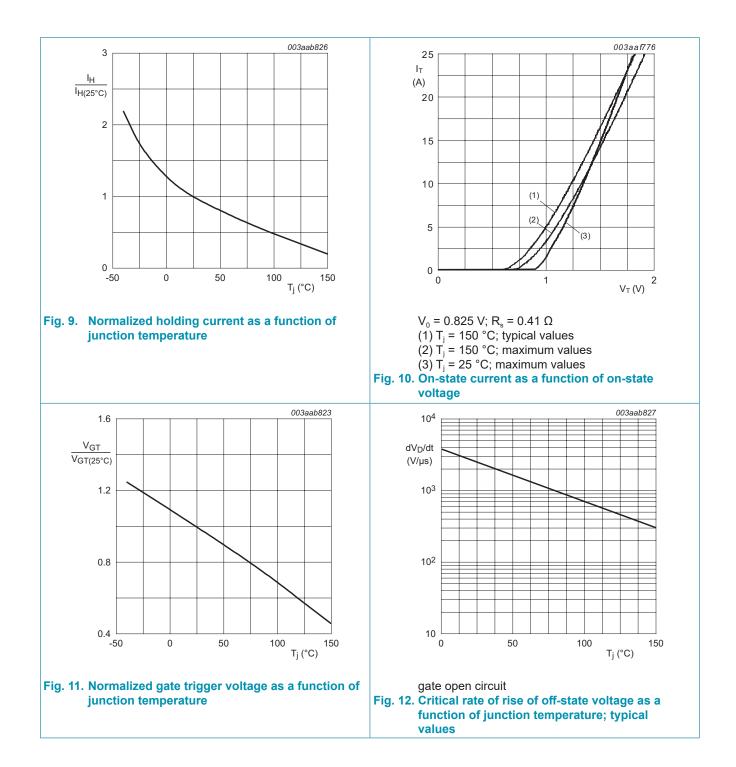




junction temperature

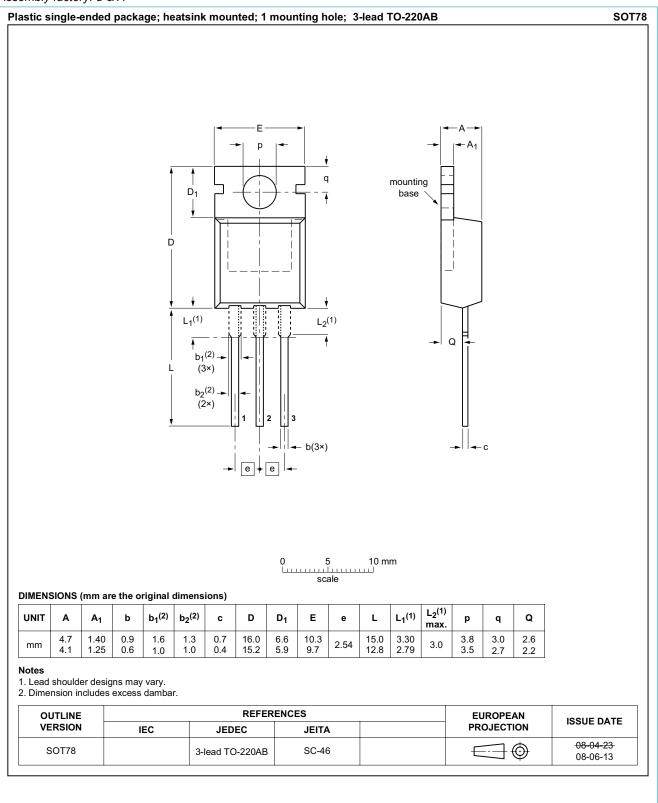
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WeEn Semiconductors



11. Package outline

Assembly factory: d & A



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12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

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